

# BRCS3019WB

Rev.B Jun.-2024

## / Descriptions

SOT-523 N MOS  
N-CHANNEL MOSFET in a SOT-523 Plastic Package.

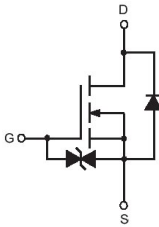
## / Features

Sensitive gate trigger current and Low Holding current.ESD protected,HF Product.

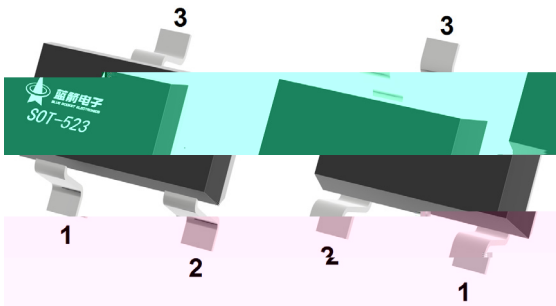
## / Applications

Intended for use in general purpose switching and phase control applications.

## / Equivalent Circuit



## / Pinning



PIN1 G      PIN 2 S      PIN 3 D

## / Marking

Marking	KN
---------	----

## / Absolute Maximum Ratings(Ta=25 )

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	50	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current	$I_D$	300	mA
Drain Current – Pulsed	$I_{DM}$	1200	mA
Power Dissipation	$P_D$	250	mW
Junction Temperature Range	$T_j$	150	
Storage Temperature Range	$T_{stg}$	-55 150	
Thermal Resistance from Junction to Ambient	$R_{JA}$	500	/W

## / Electrical Characteristics(Ta=25 )

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	$V_{DSS}$	$V_{GS}=0$ $I_D=250$ A	50			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{GS}=0$ $V_{DS}=50V$			1.0	A
Gate-Source Leakage current	$I_{GSS}$	$V_{DS}=0V$ $V_{GS}=\pm 20V$			$\pm 2$	A
Static Drain-Source On-Resistance	$R_{DS(on)(1)}$	$V_{GS}=10V$ $I_D=0.3A$		0.92	2.5	
	$R_{DS(on)(2)}$	$V_{GS}=4.5V$ $I_D=0.2A$		0.98	3	
	$R_{DS(on)(3)}$	$V_{GS}=2.5V$ $I_D=0.01A$		1.2	4.5	
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V$ $I_S=300mA$			1.2	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	0.6	0.9	1.5	V
Input Capacitance	$C_{iss}$	$V_{GS}=0V,$ $f=1MHz,$ $V_{DS}=15V$		30		pF
Output Capacitance	$C_{oss}$			5.2		
Reverse Transfer Capacitance	$C_{rss}$			3.3		
Gate Resistance	$R_g$	$V_{DS} = 0V,$ $V_{GS} = 0V,$ $f = 1MHz$		157		
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS} = 5V,$ $V_{DD}=5V,$ $R_L=500$ , $R_G=10$		15		ns
Rise Time	$t_r$			35		
Turn-Off Delay Time	$t_{d(OFF)}$			80		
Fall Time	$t_f$			80		

**/ Electrical Characteristic Curve**

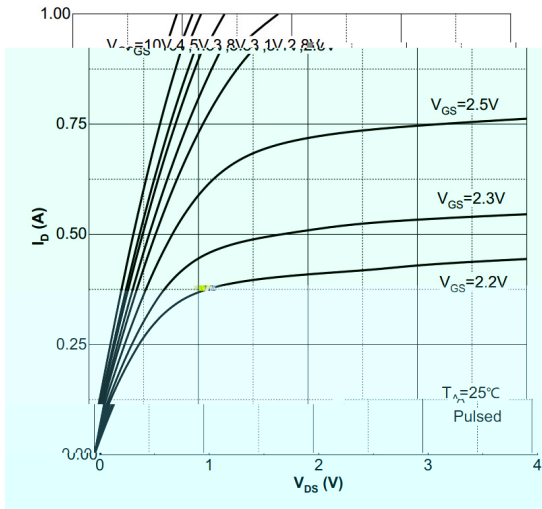


Figure 6 Output characteristics

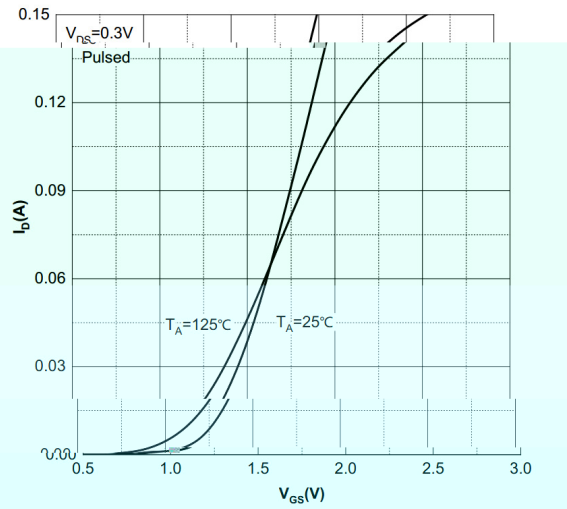


Figure 7 Transfer characteristics

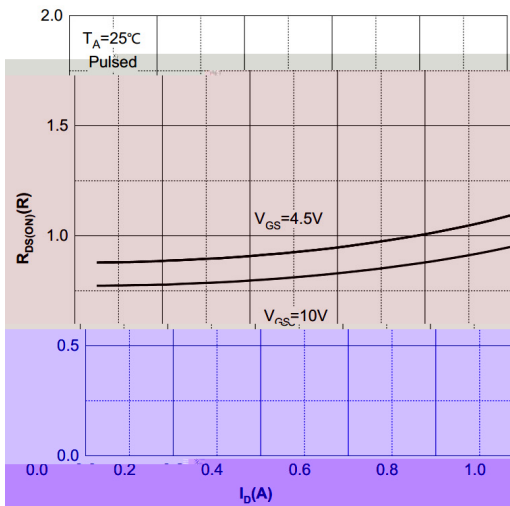


Figure 3 On-Resistance vs. Drain Current

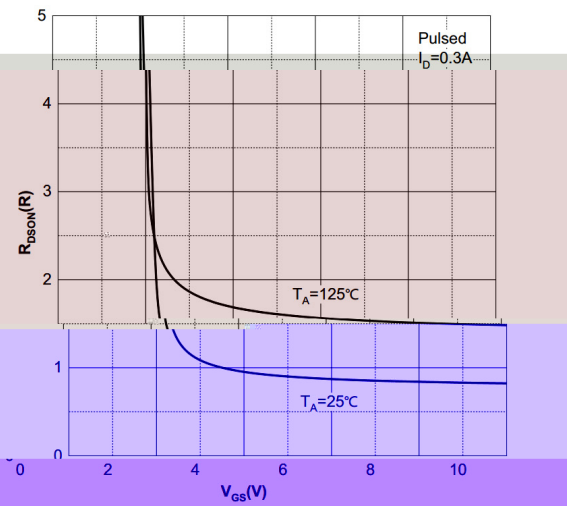
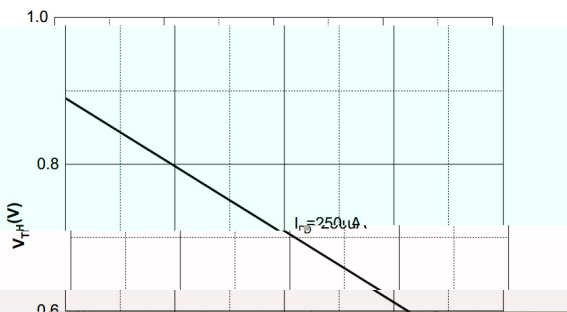
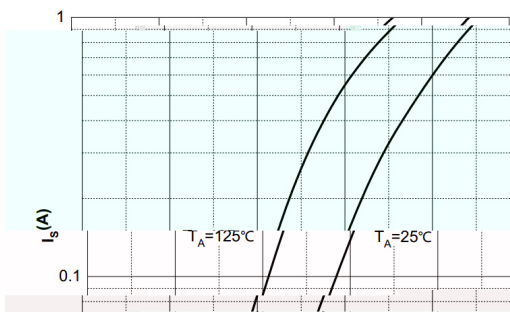


Figure 4 On-Resistance vs. Gate-Source Voltage



/ Electrical Characteristic Curve

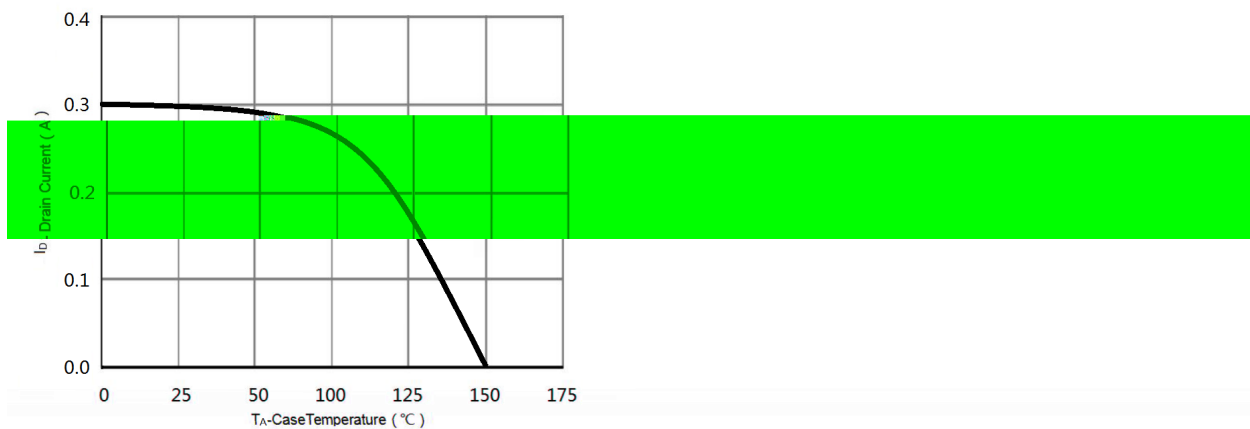
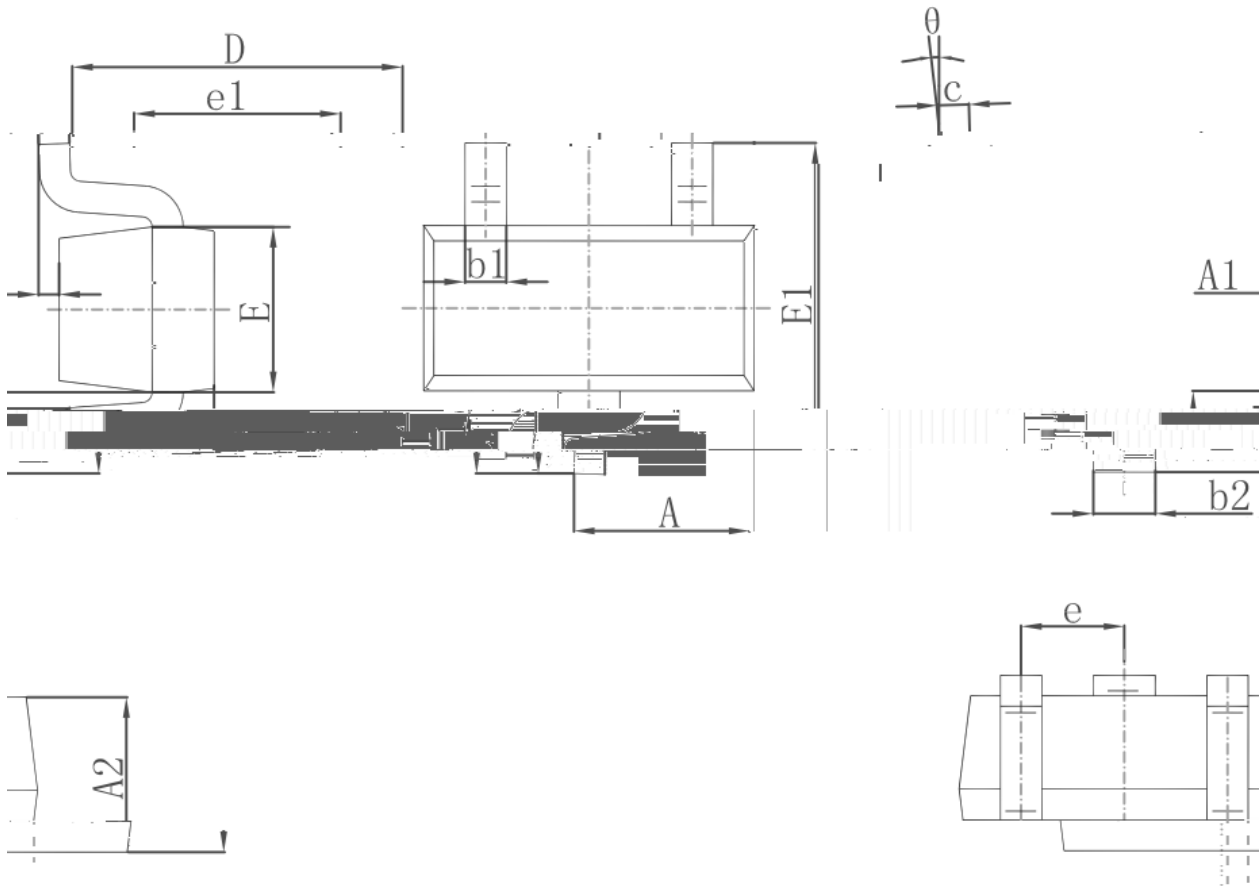


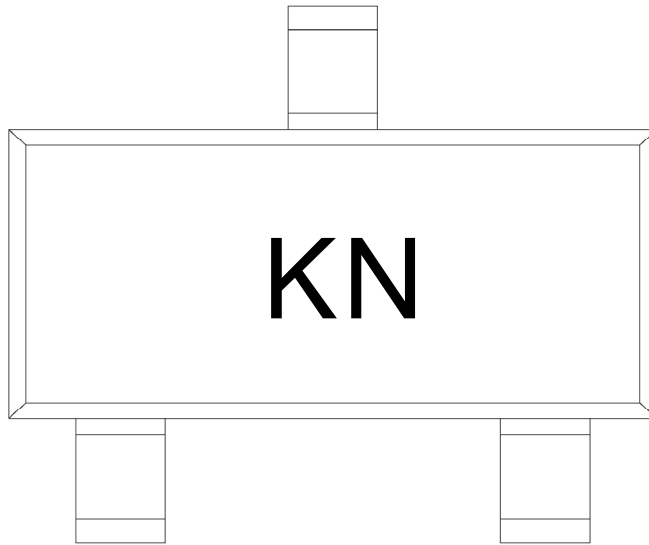
Figure 7 : Current De-rating

**/ Package Dimensions**



Dimensions In Millimeters		Dimensions In Inches		Symbol
Min.	Max.	Min.	Max.	
0.700	0.900	0.028	0.035	A
0.000	0.100	0.000	0.004	A1
0.700	0.800	0.028	0.031	A2
0.150	0.250	0.006	0.010	b1
0.250	0.350	0.010	0.014	b2
0.004	0.008		c	
0.059	0.067		D	0.100
0.028	0.035		E	1.500
		1.450	1.750	0.057
				0.069
e	0.500 TYP.			0.020 TYP.
e1	0.900	1.100		0.035
	0.400 REF.			0.016 REF.
	0.260	0.460		0.010
	0°	8°		0°
				8°

**/ Marking Instructions**

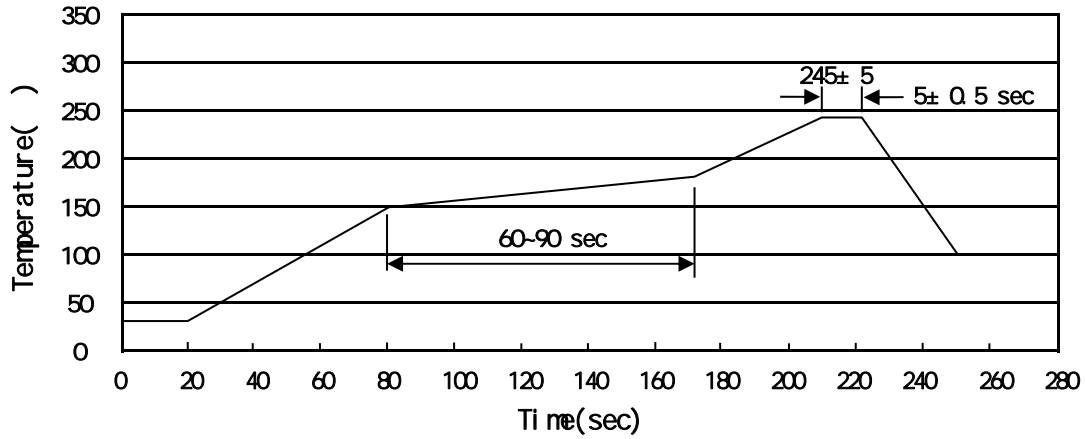


KN

Note:

KN: Product Type Code

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- |   |       |     |       |          |                                         |
|---|-------|-----|-------|----------|-----------------------------------------|
| 1 | 150   | 180 | 60    | 90sec;   | 1.Preheating:150~180 , Time:60~90sec.   |
| 2 | 245±5 |     | 5±0.5 | sec;     | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 |       |     | 2     | 10 /sec. | 3. Cooling Speed: 2~10 /sec.            |

/ Resistance to Soldering Heat Test Conditions

260±5                      10±1 sec.                      Temp.:260±5                      Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm <sup>3</sup> )		
SOT-523	3,000	10	30,000	6	180,000	7 x8	180x120x180	390x385x205

/ Notices